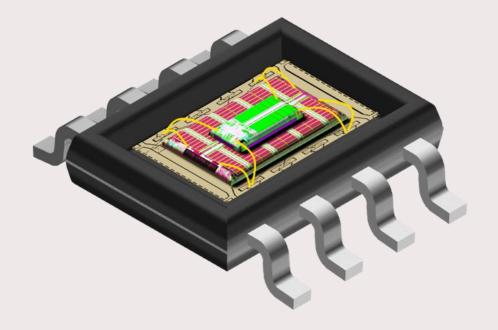




Applications of the project

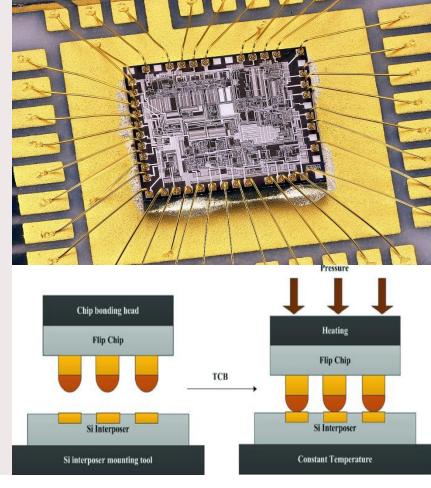
- High-tech applications
 - Speed increasingly important
 - Hardware limitations
- More and faster connections required
- Packaging





Purpose of the project

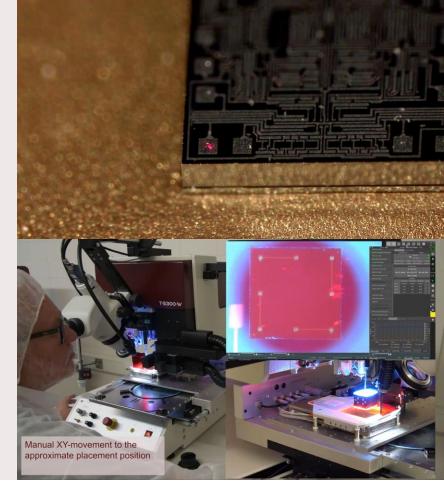
- Flip-Chip Technology vs Wire Bonding
- More interconnections
- Shorter interconnections
- Lower propagation time
- Process existence benefits TU/e projects requiring FCT





Project setup

- Proposed process: 4 stages
 - Interposer design & production
 - Bump placement
 - Die placement
 - Testing
- Developed for IC group
 - Cleanroom
 - Electronics lab

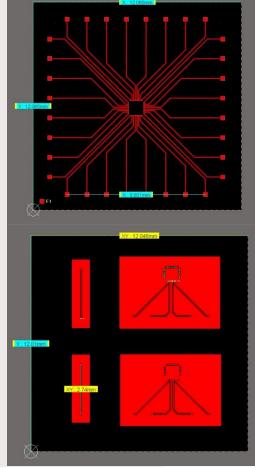




Process developments: Interposer Design

- Glass interposer
- 2 metallization methods: sputtering and evaporation
- 2 purposes: trade-off and characteristics

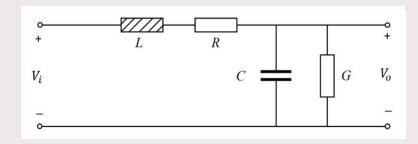


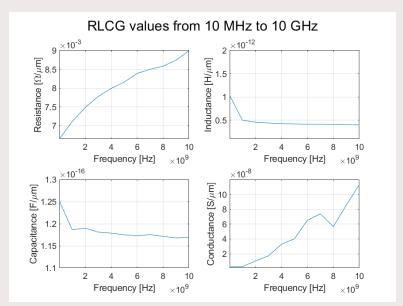




Process developments: Interposer Characterization

- 50 nm Titanium adhesion layer
- Evaporation: lower resistance, consistent bump placement







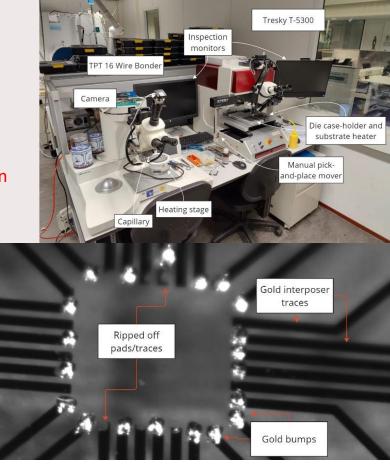
Process developments: Bumps

- 25 vs 17 um gold wire
- Good bump quality on small gold surface areas, but bad on large areas
- Reliable process
- Requires pad pitch > 90 um
- Placement method: cursor as reference

Good bump quality on small gold surface areas, but bad on large areas

Unreliable process - clogging

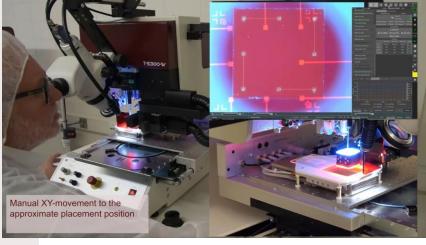
90 um pad pitch works

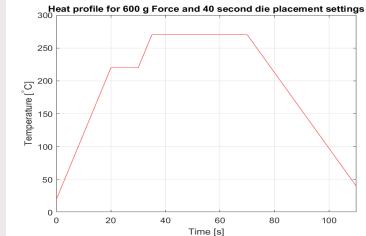




Process developments: Dies

- Heat profile, force and duration settings required
- Semi-successful attempt
- Weight distribution
- Metal connections confirmed







Final remarks

- Cooperation with Accelonix recommended
- Evaporation preferred production method
- 25 um gold wire process most reliable, but requires pad pitch size > 90 um
- Future research steps:
- 1. Improving and optimizing settings for bump and die placement
- 2. Investigate AC behaviour of tracks at frequencies >> 10 GHz
- 3. Exploring electrical characteristics of the bumps



